

B050M

Rev.H Mar.-2023

5 Ø / Dp

9 5 : .> // x 4 6 4 ! - } â Silicon NPN transistor in SOT-23 Plastic Package.

/ " / Ft

2 3 ; mo

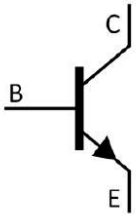
Complementary pair with L8550M.

— ÷ / Ap

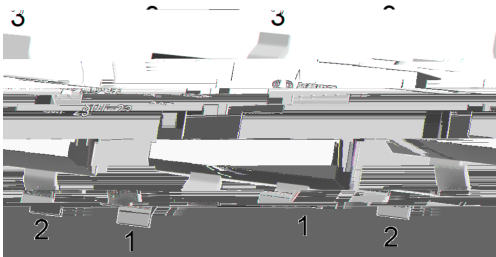
9 ä y Ý ð

Power amplifier applications.

^ W] Ô• / EtCb



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PIN 1 y Base

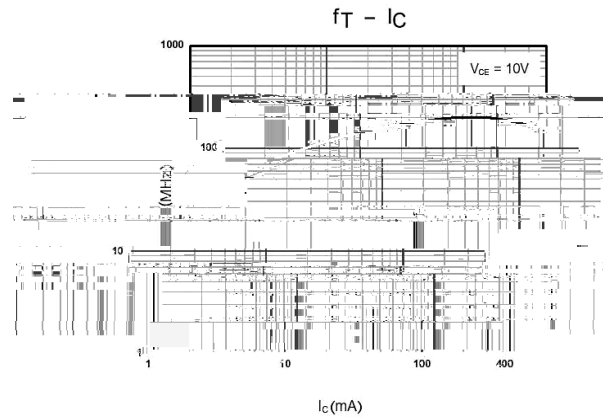
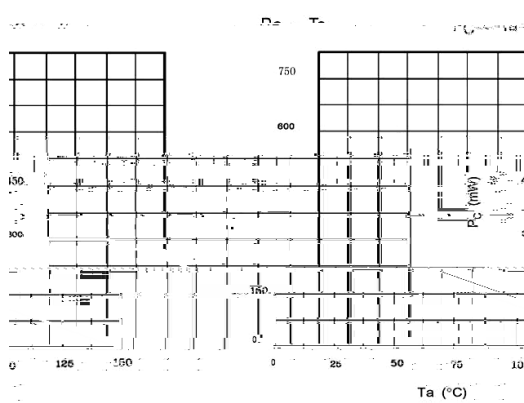
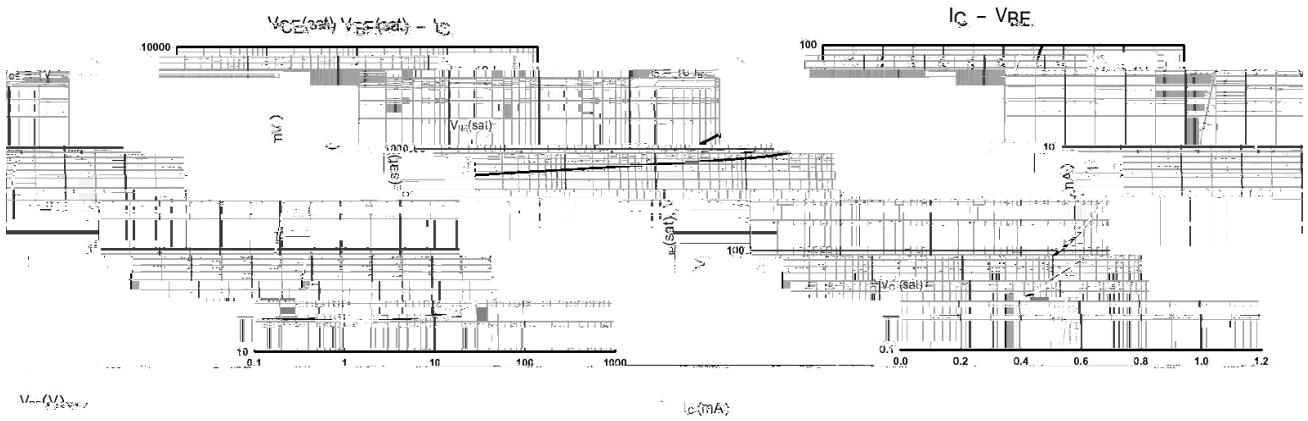
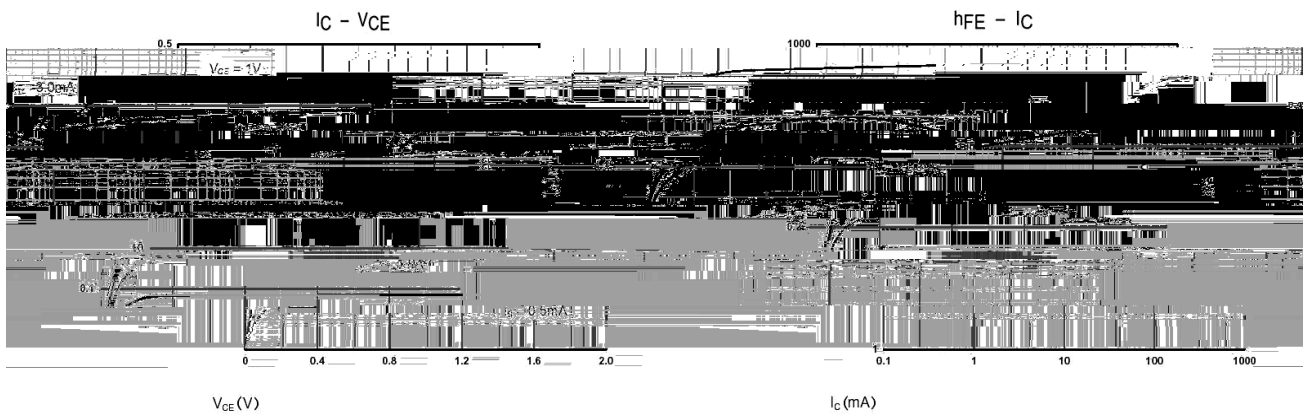
PIN 2 y Emitter

PIN 3 y Collector

Z ÜB , M V / hFE C& M

@ Parameter	Z Symbol	Rating	% y Unit
Collector to Base Voltage	V		

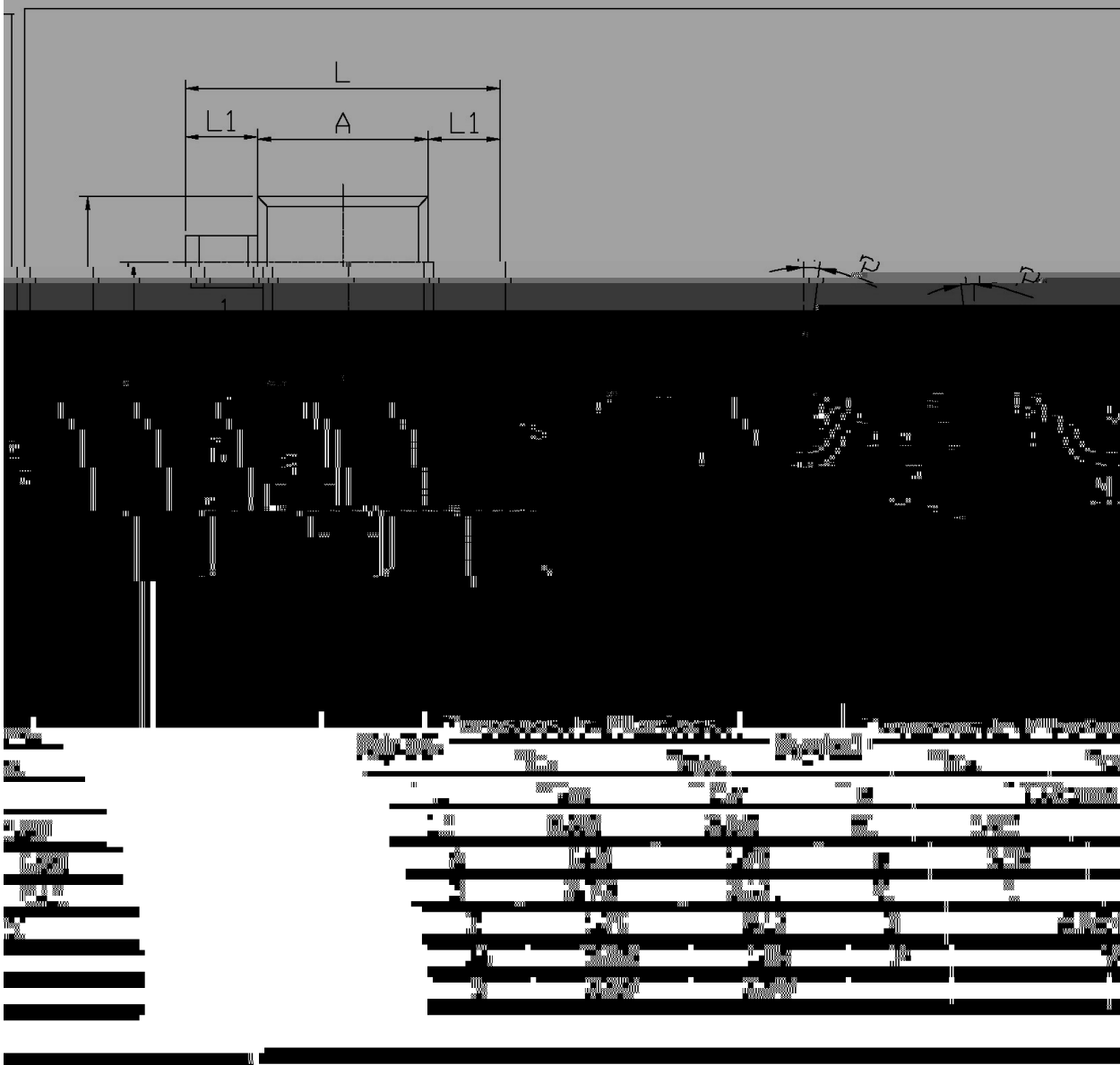
Ô? d ¢ / EtCtC



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SQT-23

单位: mm



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DATA SHEET

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DAE SEET

WD t ϕ (x /) / : K S V K X G Z [X K 6 X U L O R K L U X / 8 8 K L R U] 9 U R J K X O

" ϕ y

- 1o ~ % 150%180 - k 60%90sec;
- 2o Q 245r5 - k 4 0 5 r0.5sec;
- 3o D N ò i 00 , 2 %0 - /sec.

Note:

- 1.Preheating:150~180 Time:60~90sec.
- 2.Peak Temp.:2455 - , Duration:5r0.5sec.
- 3.Cooling Speed: 2~10- /sec.

1D /C^a p¹fl »] / 0510CH

y 260r5 - y 10 r1 sec. Temp.:2605 - Time:10r1 sec

G P Æ / 0C.

2 & x / REEL